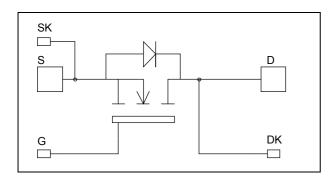


Single Switch MOSFET Power Module

$$\begin{split} V_{DSS} &= 100 V \\ R_{DSon} &= 1.5 m \Omega \text{ typ } @ \text{ Tj} = 25 ^{\circ} \text{C} \\ I_D &= 860 \text{A*} @ \text{Tc} = 25 ^{\circ} \text{C} \end{split}$$



Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS V® FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Fast intrinsic diode
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration
- AlN substrate for improved thermal performance

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		100	V
Ţ	Continuous Drain Current	$T_c = 25^{\circ}C$	860 *	
I_{D}		$T_c = 80$ °C	640 *	A
I_{DM}	Pulsed Drain current	2200		
V_{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		1.6	mΩ
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	2500	W
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A
E_{AR}	Repetitive Avalanche Energy		50	mJ
E_{AS}	Single Pulse Avalanche Energy		3000	111,7

^{*} Specification of MOSFET device but output current must be limited to 500A to not exceed a delta of temperature greater than 100°C for the connectors.

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25^{\circ}C$			500	A	
		$V_{GS} = 0V, V_{DS} = 80V$	$T_j = 125$ °C			2000	μΑ	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 275A$			1.5	1.6	mΩ	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 12mA$		2		4	V	
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$	V			±450	nA	

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		60		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		23		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		8.8		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		2100		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 50V$		360		nC
Q_{gd}	Gate – Drain Charge	$I_D = 550A$		1080		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching $V_{GS} = 15V$ $V_{Bus} = 66V$		185		
$T_{\rm r}$	Rise Time			270		
T _{d(off)}	Turn-off Delay Time	$I_{D} = 550A$		600		ns
T_{f}	Fall Time	$R_G = 1\Omega$		175		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		3.3		m I
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 550A, R_G = 1\Omega$		3.6		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		3.65		m I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 550A, R_G = 1\Omega$		3.85		mJ

Source - Drain diode ratings and characteristics

Source - Drain Glode ratings and characteristics							
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$			860*	A
	(Body diode)		$Tc = 80^{\circ}C$			640*	А
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -550A$				1.3	V
dv/dt	Peak Diode Recovery •					5	V/ns
t _{rr}	Reverse Recovery Time		$T_j = 25$ °C			190	ns
·rr	reverse receivery Time	$I_S = -550A$ $V_R = 66V$	$T_j = 125$ °C			370	115
Q _{rr}	Reverse Recovery Charge	$di_{S}/dt = 600A/\mu s$	$T_j = 25^{\circ}C$		2.4		μC
	reverse receivery charge		$T_j = 125$ °C		10.2		μ

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

 $I_S \leq \text{--}~860A \qquad \text{di/dt} \leq 600 \text{A/}\mu \text{s} \qquad V_R \leq V_{DSS} \qquad \quad T_j \leq 150^{\circ}\text{C}$

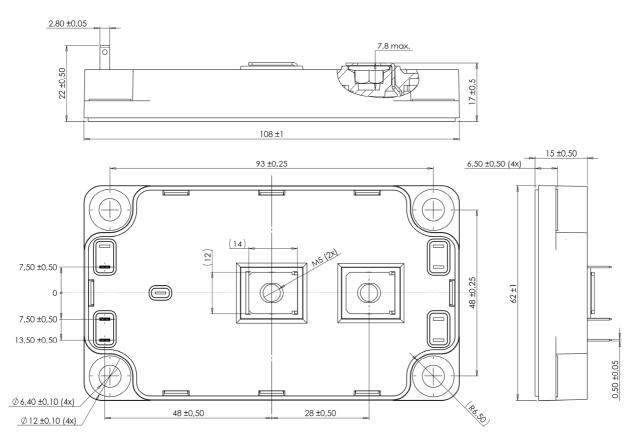
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Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					0.05	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150	°C	
T _{STG}	Storage Temperature Range			-40			125
$T_{\rm C}$	Operating Case Temperature			-40			100
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Torque		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

SP6 Package outline (dimensions in mm)

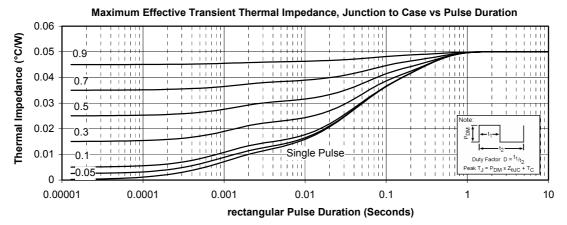


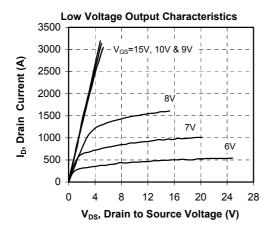
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

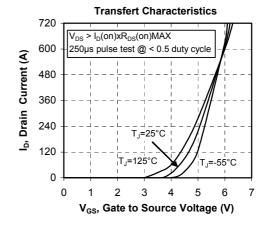
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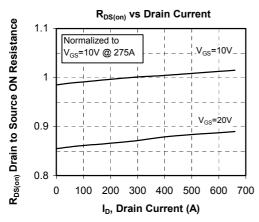


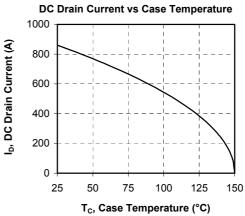
Typical Performance Curve



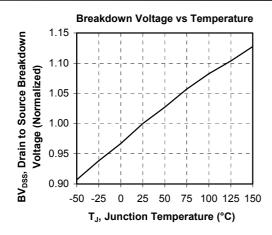


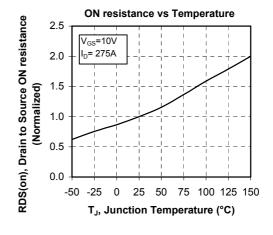


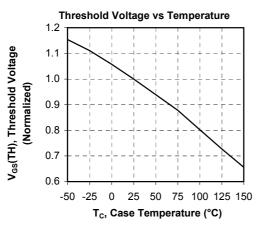


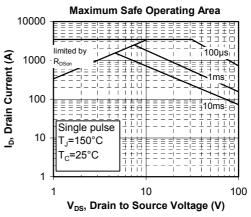


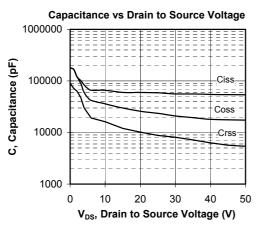


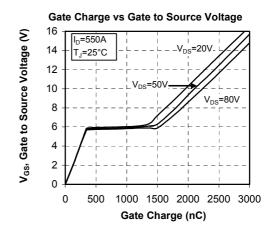






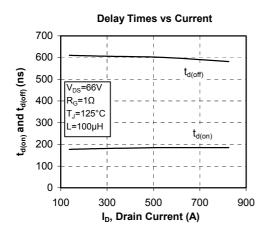


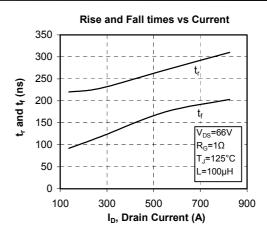


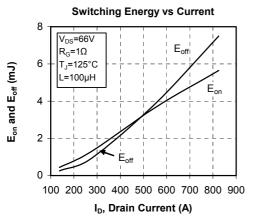


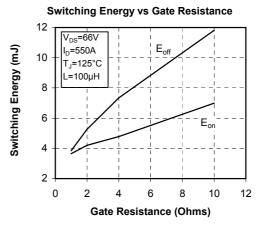
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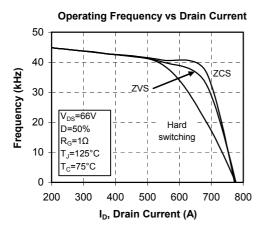


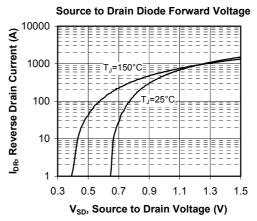














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